

PS-C5

# Effect of Interlayer Spin-flip Tunneling for Interlayer Magnetoresistance in Multilayer Dirac Fermion Systems

Kenji Kubo

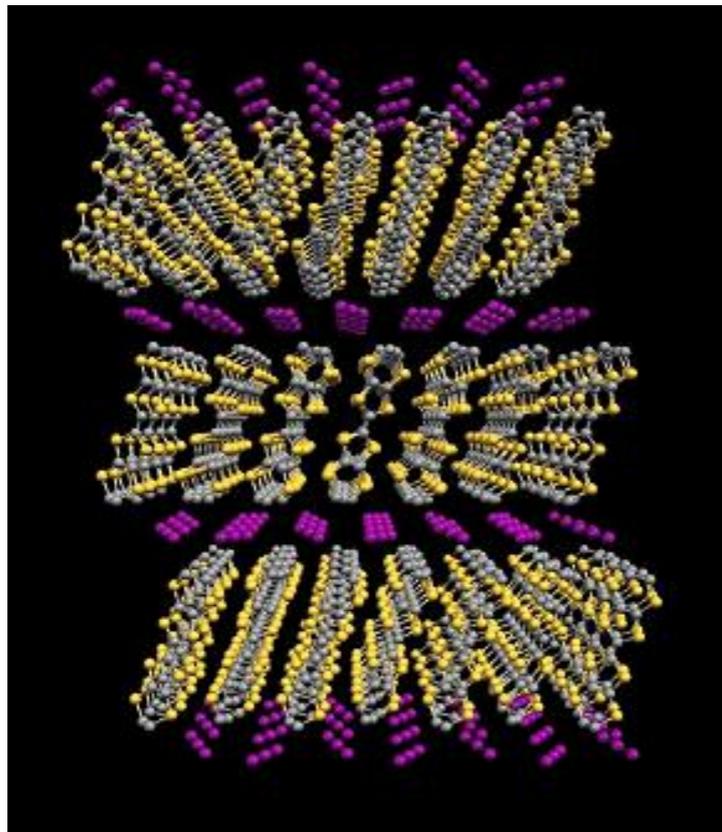
Collaborator Takao Morinari

Graduate School of Human and Environmental Studies,  
Kyoto University

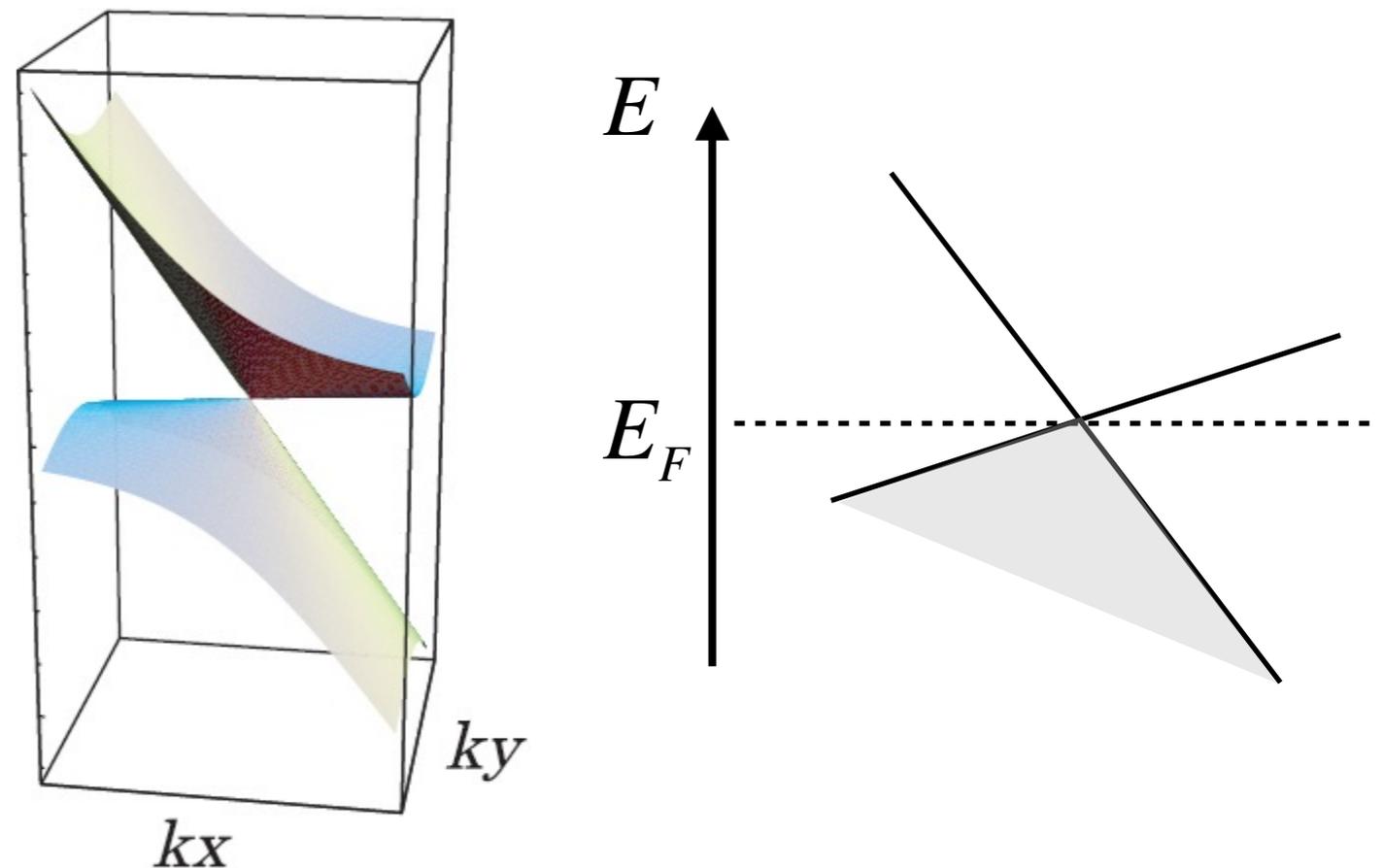
K. Kubo, T. Morinari, J. Phys. Soc. Jpn. **83**, 083701 (2014)

# $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>

- **Dirac fermion system** under high pressure Tajima et al., 2000, 2006
- **Multilayered system** with conducting layers of BEDT-TTF molecules and insulating layers of I<sub>3</sub> anions.



N. Tajima, (RIKEN)

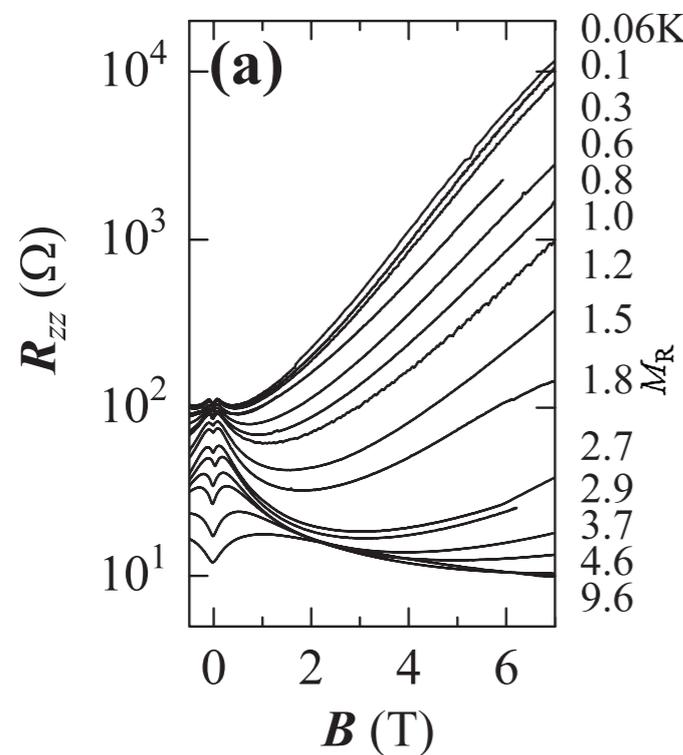


A. Kobayashi et al., (2004)

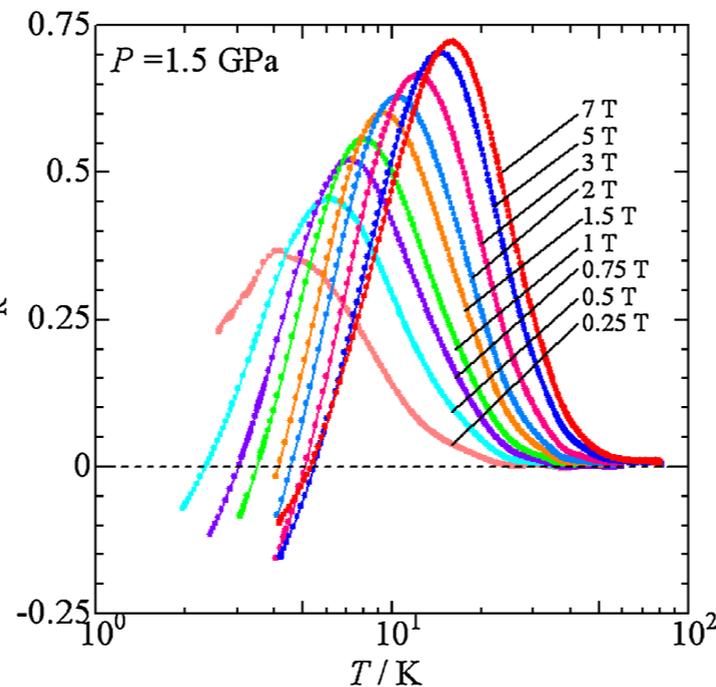
S. Katayama, A. Kobayashi, Y. Suzumura, (2006)

# Motivation

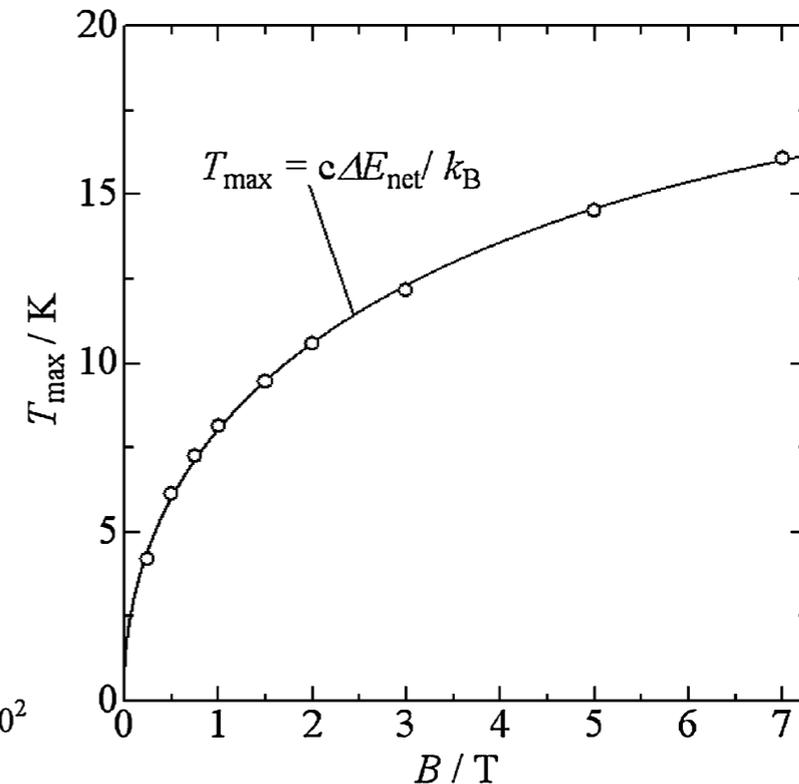
- $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub> has unique interlayer magnetoresistance



N. Tajima et al., (2009)



S. Sugawara et al, (2010)

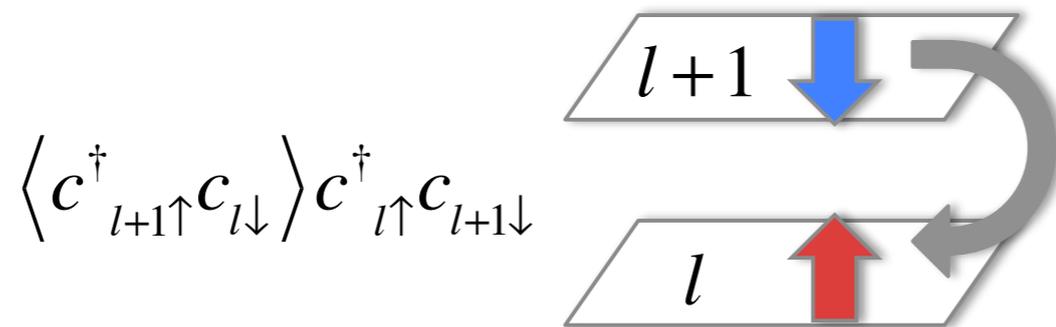


- Previous theoretical research :  $T_{\max} = C\sqrt{B}$  T. Morinari and T. Tohyama, (2010)
- Experimental result :  $T_{\max} = C\sqrt{B} - g\mu_B B$   
 → Peak temperature is shifted by the Zeeman energy.
- The interlayer tunneling should be related to spin-flip processes.

# Results

- The opposite spin mean field arise from the interlayer Coulomb interaction

- The opposite spin mean field leads the interlayer spin-flip tunneling



- The peak temperature of the interlayer magnetoresistance is shifted by the Zeeman energy.

